

#### 300V NPN HIGH-VOLTAGE TRANSISTOR IN SOT23

### **Description**

This bipolar junction transistor (BJT) is designed to meet the stringent requirements of automotive applications.

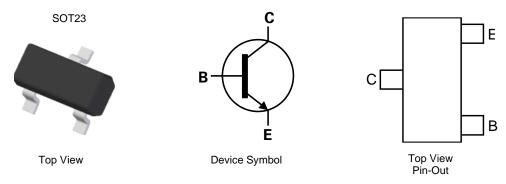
#### **Features**

- BVcEo > 300V
- Ic = 200mA High Collector Current
- 350mW Power Dissipation
- Excellent her Characteristics Up To 30mA
- Complementary Part Number: FMMTA92Q
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The FMMTA42Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions

### **Mechanical Data**

- Package: SOT23
- Package Material: Molded Plastic. "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.008 grams (Approximate)



# Ordering Information (Note 4)

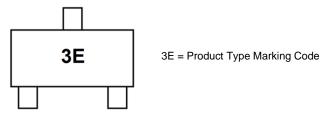
Orderable Part Number	Dookses Marking Dook Sing (inches		Reel Size (inches)	Tone Width (mm)	Packing	
Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Qty.	Carrier
FMMTA42QTA	SOT23	3E	7	8	3000	Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
- <1000ppm antimony compounds.

  4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**





### **Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	300	V
Collector-Emitter Voltage	VCEO	300	V
Emitter-Base Voltage	VEBO	7	V
Collector Current	Ic	200	mA

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	D-	310	mW	
Power Dissipation	(Note 6)	PD	350		
Thermal Desigtance, Junction to Ambient	(Note 5)	Davis	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	Rөja	357	C/VV	
Thermal Resistance, Junction to Leads (Note 7)		R <sub>OJL</sub>	350	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

# ESD Ratings (Note 8)

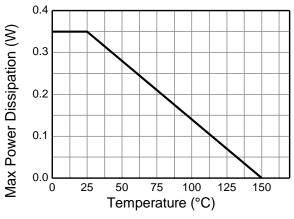
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge—Machine Model	ESD MM	400	V	С

Notes:

- 5. For the device mounted on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady state condition.
- 6. Same as Note 5, except the device is mounted on 15mm x 15mm 1oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the leads).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**



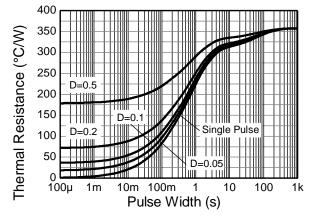
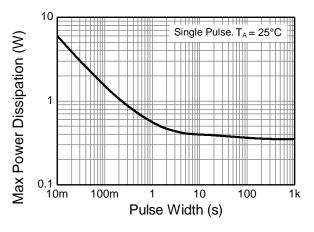
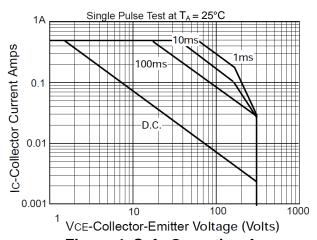


Figure 1. Derating Curve

Figure 2. Transient Thermal Impedance





**Figure 3. Pulse Power Dissipation** 

Figure 4. Safe Operating Area



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

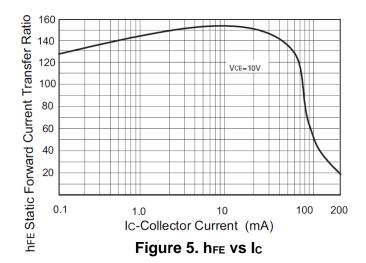
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	300	_	_	V	Ic = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BVceo	300	_	_	V	Ic = 1mA
Emitter-Base Breakdown Voltage	BVEBO	7	_	_	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	Ices	_	_	100	nA	Vce = 200V
Collector Cutoff Current	Ісво	_	_	100	nA	V <sub>CB</sub> = 200V
Emitter Cutoff Current	IEBO	_	_	100	nA	V <sub>EB</sub> = 6V
Static Forward Current Transfer Ratio (Note 9)	hFE	25 40 40	_	_	_	I <sub>C</sub> = 1mA, V <sub>CE</sub> = 10V I <sub>C</sub> = 10mA, V <sub>CE</sub> = 10V I <sub>C</sub> = 30mA, V <sub>CE</sub> = 10V
Collector-Emitter Saturation Voltage (Note 9)	VcE(sat)	_	_	500	mV	Ic = 20mA, I <sub>B</sub> = 2mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	_	_	900	mV	$I_C = 20$ mA, $I_B = 2$ mA
Output Capacitance	Cobo	_	_	6	pF	V <sub>CB</sub> = 20V, f = 1MHz
Transition Frequency	f⊤	50	_	_	MHz	V <sub>CE</sub> = 20V, I <sub>C</sub> = 10mA, f = 20MHz

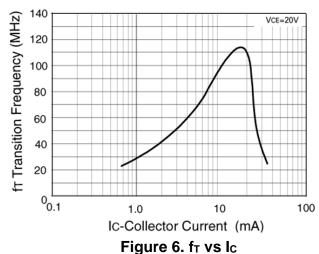
Note:

9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



# $\hline \textbf{Typical} \ \underline{\textbf{Electrical Characteristics}} \ (@T_A = +25^{\circ}C, \text{ unless otherwise specified.}) \\$





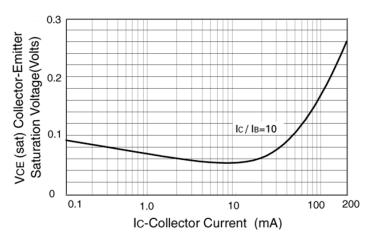


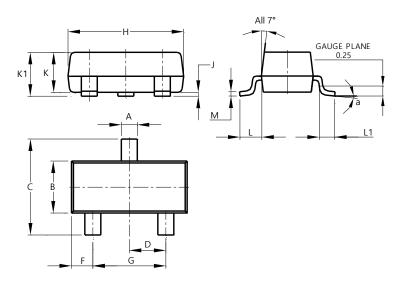
Figure 7.  $VCE_{(sat)}$  vs  $I_C$ 



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

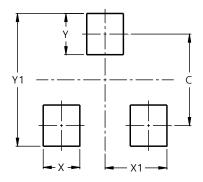


SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	0°	8°	_		
All Dimensions in mm					

# **Suggested Pad Layout**

 $\label{lem:please} Please see \ http://www.diodes.com/package-outlines.html \ for the \ latest \ version.$ 

#### SOT23



Dimensions	Value (in mm)		
C	2.0		
Х	0.8		
X1	1.35		
Y	0.9		
Y1	2.9		

October 2024



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